



HFZT

SA1 ----- S1M

PLASTIC SILICON RECTIFIERS

VOLTAGE RANGE: 50 --- 1000 V
CURRENT: 6.0 A

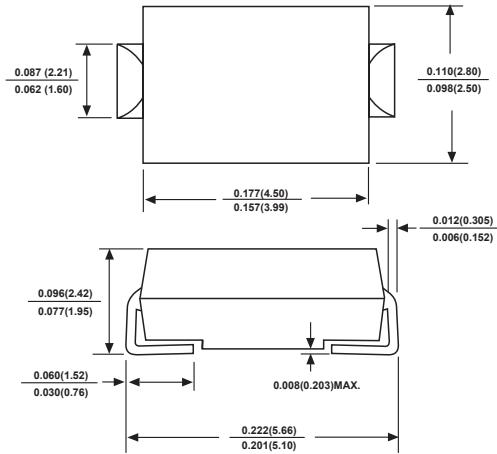
FEATURES

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- Construction utilizes void-free molded plastic technique
- For surface mounted applications
- Built-in strain relief, ideal for automated placement
- High temperature soldering guaranteed: 260°C/10 seconds at Terminals
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

MECHANICAL DATA

- Case:SMA molded plastic body
- Terminals:Lead solderable per MIL-STD-750,method 2026
- Polarity:Color band denotes cathode end
- Mounting Position:Any

SMA



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND CHARACTERISTICS

@ 25°C Ambient Temperature (unless otherwise noted) Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate by 20%.

Characteristic	SYMBOLS	S1A	S1B	S1D	S1G	S1J	S1K	S1M	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum DC blocking voltage	V_{DC}								
Maximum RMS Voltage	$V_{R(RMS)}$	35	70	140	280	420	560	700	V
Average rectified output current(Note 1)@TA=75°C	$I_{(AV)}$					1.0			A
Non-Repetitive Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load(JEDECmethod)	I_{FSM}					30.0			A
Maximum instantaneous forward voltage at 1.0A	V_F				1.0				V
Maximum DC reverse current at rated DC blocking voltage	$\begin{array}{l} @T_A=25 \\ @T_A=100 \end{array}$	I_{RM}			5.0				μA
					50.0				
Typical Junction Capacitance(Note 1)	C_J				15				pF
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$				85				$^{\circ}C/W$
Operating junction and storage temperature range	T_j				-65 to +175				$^{\circ}C$

Note:

1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. Thermal resistance junction to ambient,P.C.B. mounted with 0.2x0.2 "(5.0x5.0mm) copper pad areas



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RATINGS AND CHARACTERISTIC CURVES

FIG. 1- FORWARD CURRENT DERATING CURVE

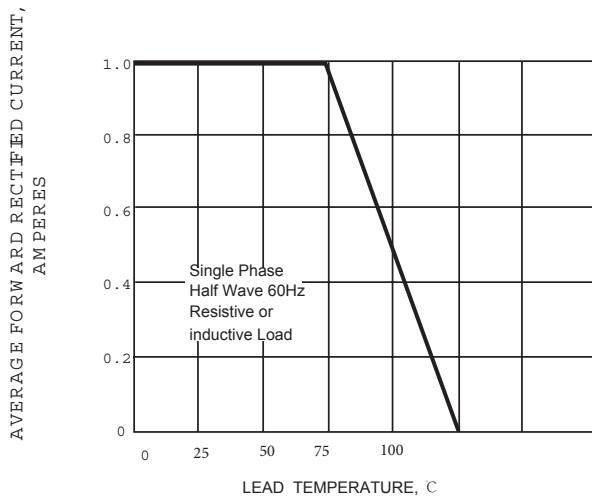


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

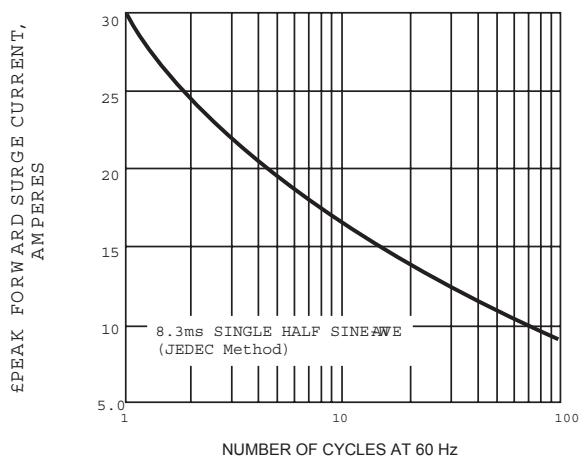


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

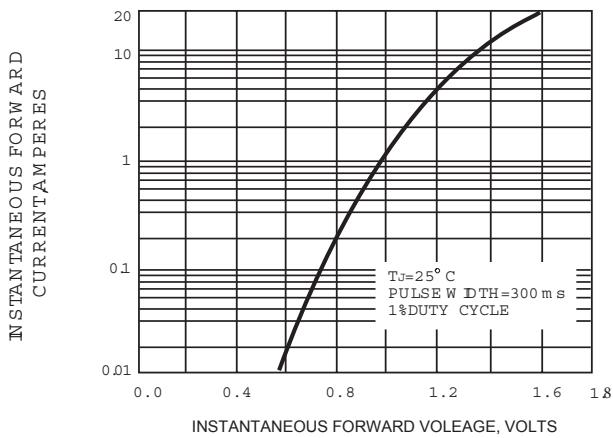


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

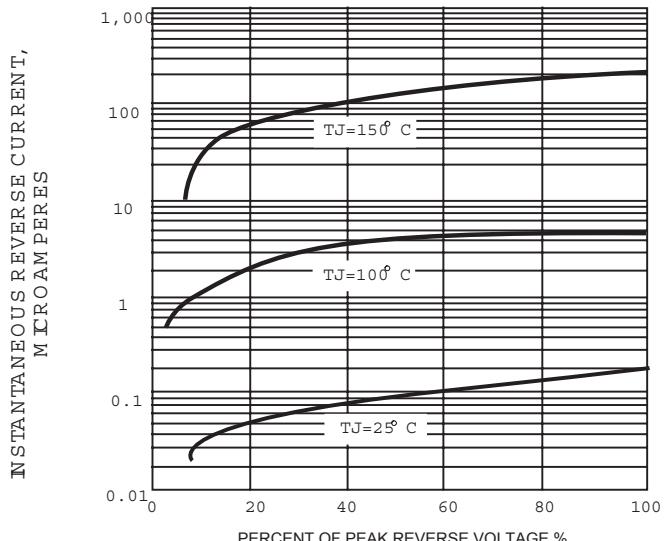
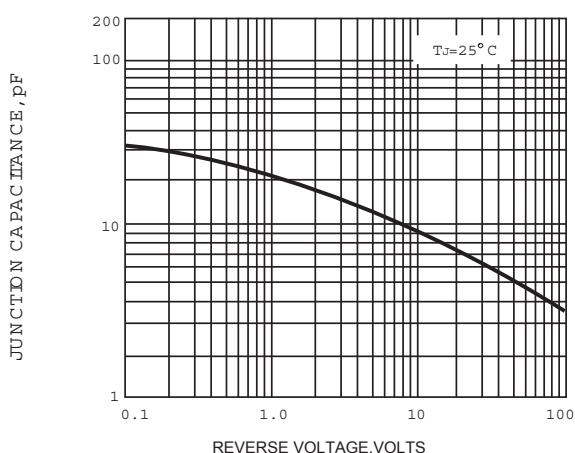


FIG. 5-TYPICAL JUNCTION CAPACITANCE



F1G.6-TYPICAL TRANSIENT THERMAL IMPEDANCE

